## NSN 5961-01-036-8409

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-036-8409 **Inclosure Material:** Plastic **Overall Length:** 2.000 inches **Overall Height:** 0.750 inches **Overall Width:** 0.750 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 2000.0 reverse voltage, peak **Current Rating Per Characteristic:** 6.00 microamperes forward current, average major **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Test Data Document:** 18876-10186139 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 turret Shelf Life: N/a **Unit Of Measure: Demilitarization:** No